

2N6394-2N6399

High-reliability discrete products and engineering services since 1977

SILICON CONTROLLED RECTIFIERS

FEATURES

- Available as "HR" (high reliability) screened per MIL-PRF-19500, JANTX level. Add "HR" suffix to base part number.
- Available as non-RoHS (Sn/Pb plating), standard, and as RoHS by adding "-PBF" suffix.

MAXIMUM RATINGS

Rating	Symbol	Value	Unit	
Peak repetitive forward and reverse blocking voltage $^{(1)}$				
(T」= -40 to +125°C, sine wave, 50 to 60 Hz, gate open)				
2N6394		50		
2N6395	VRRM. VDRM	100	Volts	
2N6396	V RRM, V DRM	200	Voits	
2N6397		400		
2N6398		600		
2N6399		800		
On state RMS current				
(180° conduction angles, T _c = 90°C)	I _{T(RMS)}	12	Amps	
Peak non-repetitive surge current			Amos	
(1/2 cycle, 60Hz, sine wave, T _J = 90°C)	I _{TSM}	100	Amps	
Circuit fusing considerations (t = 8.3ms)	l²t	40	A ² s	
Forward peak gate power (pulse width $\leq 1.0 \mu s$, T _c = 90 \degree °C)	P _{GM}	20	Watts	
Forward average gate power (t = 8.3ms, T _c = 90°C)	P _{G(AV)}	0.5	Watts	
Forward peak gate current (pulse width ≤ 1.0 μ s, T _C = 90്°C)	I _{GM}	2	Amps	
Operating junction temperature range	TJ	-40 to +125	°C	
Storage temperature range	T _{stg}	-40 to +150	°C	

Note 1: VDRM and VRRM for all types can be applied on a continuous basis without incurring damage. Ratings apply for zero or negative gate voltage; however, positive gate voltage shall not be applied concurrent with negative potential on the anode. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Maximum	Unit
Thermal resistance, junction to case	Rejc	2.0	°C/W
Maximum lead temperature for soldering purposes 1/8" from case for 10 seconds	ΤL	260	°C

ELECTRICAL CHARACTERISTICS (T_C = 25°C)

Characteristic	Symbol	Min.	Тур.	Max.	Unit
OFF CHARACTERISTICS					
Peak forward or reverse blocking current (V_{AK} = Rated V_{DRM} or V_{RRM} , gate open) T _J = 25°C T _J = 100°C	I _{DRM} OT I _{RRM}	-	-	10 2.0	μA mA
ON CHARACTERISTICS					
Peak forward on-state voltage (2) (I _{TM} = 24A peak)	V _{TM}	-	1.7	2.2	Volts
Gate trigger current (continuous dc) $(V_D = 12 \text{ Vdc}, R_L = 100 \Omega)$	Igt	-	5.0	30	mA



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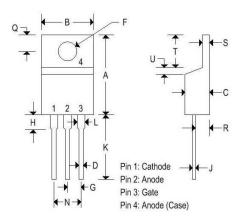
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Characteristic	Symbol	Min.	Тур.	Max.	Unit
OFF CHARACTERISTICS					
Gate trigger voltage (continuous dc)	V _{GT}				Volts
$(V_D = 12 \text{ Vdc}, R_L = 100 \Omega)$	VGT	-	0.7	1.5	VOILS
Gate non-trigger voltage					Volts
$(V_D = 12 \text{ Vdc}, R_L = 100 \Omega, T_J = 125^{\circ}\text{C})$	V _{GD}	0.2	-	-	VOITS
Holding current					
$(V_D = 12Vdc, initiating current = 200mA, gate open)$	Iн	-	6.0	50	mA
Turn on time					
(I_{TM} = 12A, I_{GT} = 40mAdc, V_D = rated V_{DRM})	t _{gt}	-	1.0	2.0	μs
Turn-off time (V _D = rated V _{DRM})	tq				μs
(I _{TM} = 12A, I _R = 12A)		-	15	-	
(I _{TM} = 12A, I _R = 12A, T _J = 125°C)		-	35	-	
DYNAMIC CHARACTERISTICS					
Critical rate of rise of off-state voltage exponential	dv/dt				V/µs
$(V_D = rated V_{DRM}, T_J = 125^{\circ}C)$		-	50	-	

MECHANICAL CHARACTERISTICS

Case:	ТО-220АВ
Marking:	Body painted, alpha-numeric
Pin out:	See below



	TO-220AB				
	Inches		Millimeters		
	Min	Max	Min	Max	
Α	0.575	0.620	14.600	15.750	
В	0.380	0.405	9.650	10.290	
С	0.160	0.190	4.060	4.820	
D	0.025	0.035	0.640	0.890	
F	0.142	0.147	3.610	3.730	
G	0.095	0.105	2.410	2.670	
Н	0.110	0.155	2.790	3.930	
J	0.014	0.022	0.360	0.560	
K	0.500	0.562	12.700	14.270	
L	0.045	0.055	1.140	1.390	
Ν	0.190	0.210	4.830	5.330	
Q	0.100	0.120	2.540	3.040	
R	0.080	0.110	2.040	2.790	
S	0.045	0.055	1.140	1.390	
Т	0.235	0.255	5.970	6.480	
U		0.050		1.270	
۷	0.045	320	1.140	1963	
Z		0.080	38	2.030	

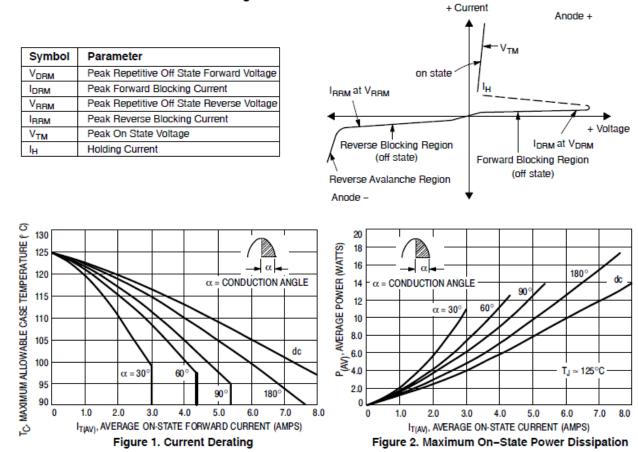


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Voltage Current Characteristic of SCR

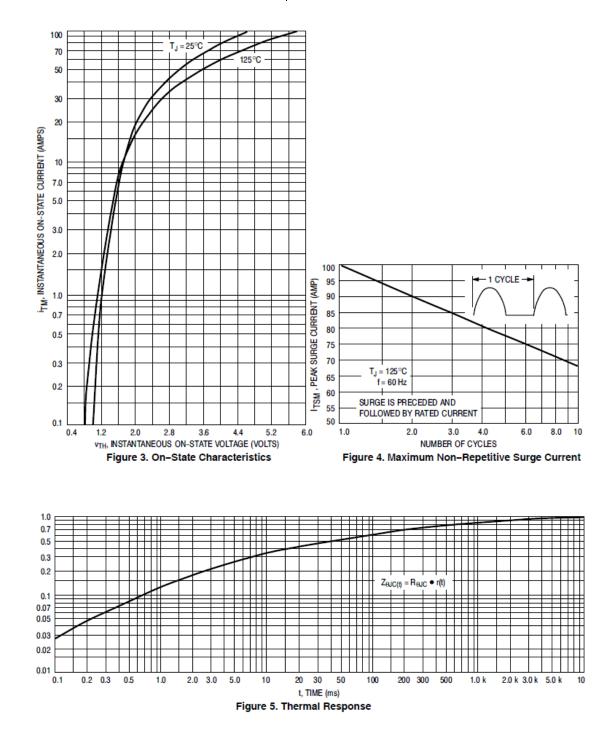




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